

DMN1019USN-13

DMN1019USN-13 Information

www.helsener.co	 DMN1019USN-13 Diodes Incorporated Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 12V 9.3A SC59 TO-236-3, SC-59, SOT-23-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



DMN1019USN-13 Specifications

Manufacturer Part Number	DMN1019USN-13
Manufacturer	Diodes Incorporated
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	12V
Current - Continuous Drain (Id) @ 25°C	9.3A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.2V, 2.5V
Vgs(th) (Max) @ Id	800mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50.6nC @ 8V
Input Capacitance (Ciss) (Max) @ Vds	2426pF @ 10V
Vgs (Max)	$\pm 8 V$
FET Feature	-
Power Dissipation (Max)	680mW (Ta)
Rds On (Max) @ Id, Vgs	10 mOhm @ 9.7A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	SC-59
Package / Case	TO-236-3, SC-59, SOT-23-3
	Report errors?

DMN1019USN-13 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DMN1019USN-13 Payment Methods



DMN1019USN-13 Shipping Methods



If you have any question about DMN1019USN-13, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com